TKMMBTA44

TRANSISTOR (NPN)

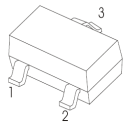
SOT-23 Plastic-Encapsulate Transistors

FEATURES

- High Collector-Emitter Voltage
- Complement to TKMMBTA94

MARKING: 3D

SOT－23



1. BASE
2. EMITTER
3. COLLECTOR

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

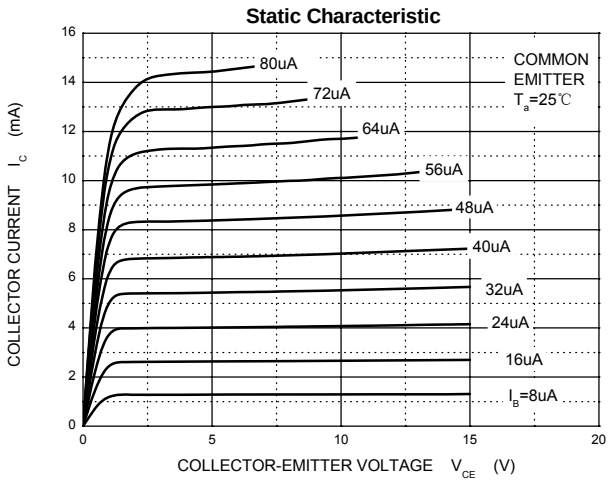
Symbol	Parameter	Value	Unit	
V_{CBO}	Collector-Base Voltage	400	V	
V_{CEO}	Collector-Emitter Voltage	400	V	
V_{EBO}	Emitter-Base Voltage	6	V	
I_C	Collector Current-Continuous	200	mA	
I_{CM}	Collector Current -Pulsed	300	mA	
P_C	Collector Power Dissipation	350	mW	
$R_{\Theta JA}$	Thermal Resistance From Junction To Ambient	357	℃/W	
T_j	Junction Temperature	150	℃	
T_{stg}	Storage Temperature	-55～+150	℃	

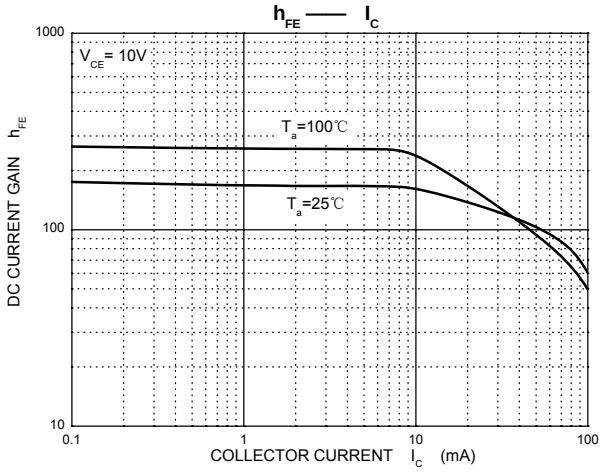
ELECTRICAL CHARACTERISTICS (T_a=25℃ unless otherwise specified)

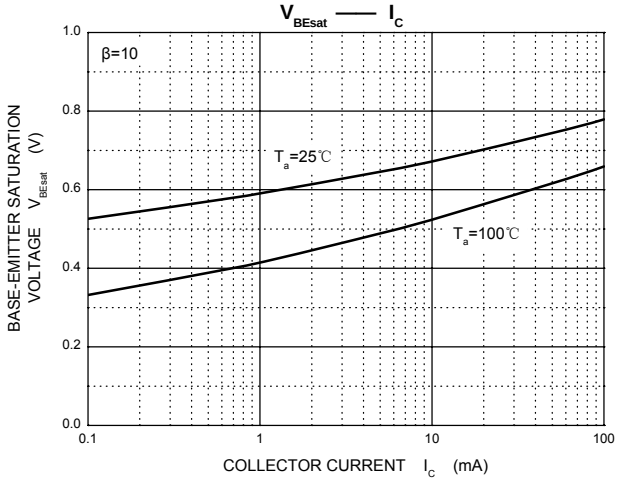
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	I_C=100μA, I_E=0	400			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$*	I_C=1mA, I_B=0	400			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I_E=10μA, I_C=0	6			V
Collector cut-off current	I_{CBO}	V_{CB}=400V, I_E=0			0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB}=4V, I_C=0			0.1	μA
DC current gain	$h_{FE(1)}$ *	V_{CE}=10V, I_C=1mA	40			
	$h_{FE(2)}$ *	V_{CE}=10V, I_C=10mA	50		200	
	$h_{FE(3)}$ *	V_{CE}=10V, I_C=50mA	45			
	$h_{FE(4)}$ *	V_{CE}=10V, I_C=100mA	40			
Collector-emitter saturation voltage	$V_{CE(sat)1}$*	I_C=1mA, I_B=0.1mA			0.4	V
	$V_{CE(sat)2}$*	I_C=10mA, I_B=1mA			0.5	V
	$V_{CE(sat)3}$*	I_C=50mA, I_B=5mA			0.75	V
Base-emitter saturation voltage	$V_{BE(sat)}$*	I_C=10mA, I_B=1mA			0.75	V
Collector output capacitance	C_{ob}	V_{CB}=20V, I_E=0, f=1MHz			7	pF
Emitter input capacitance	C_{ib}	V_{EB}=0.5V, I_C=0, f=1MHz			130	pF

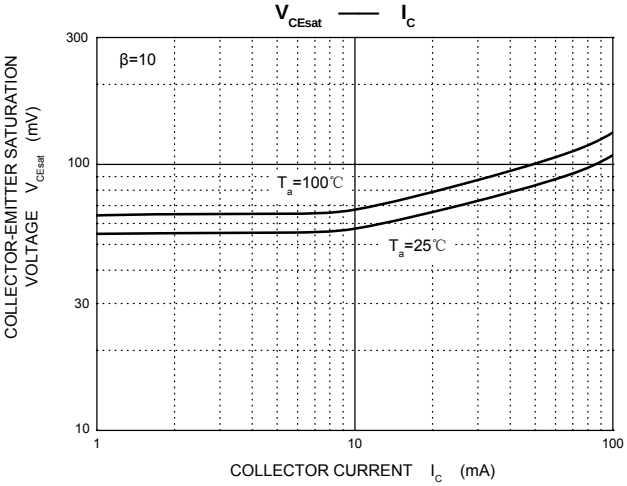
*Pulse test: pulse width ≤300μs, duty cycle≤ 2.0%.

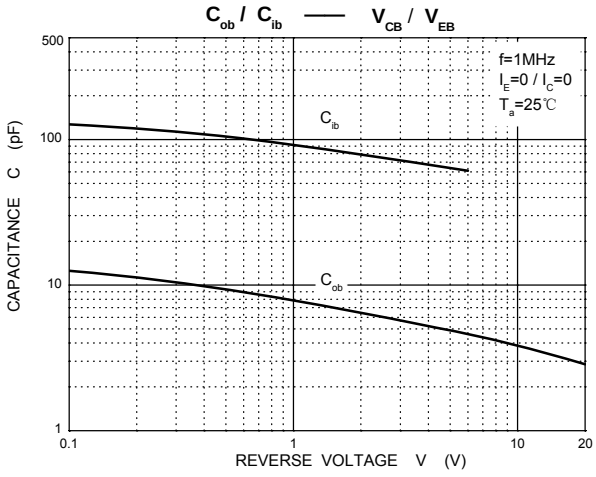
Typical Characteristics

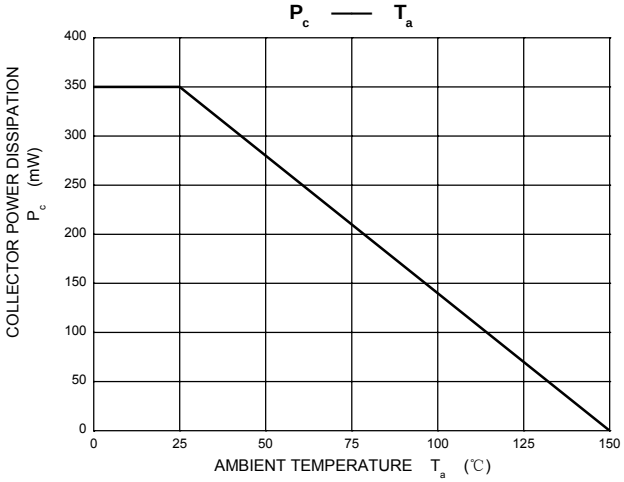


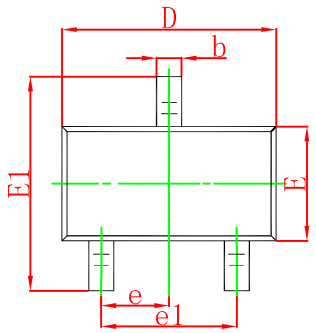


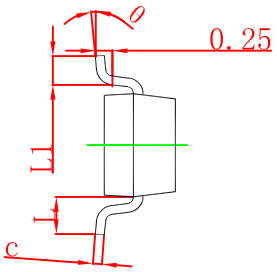


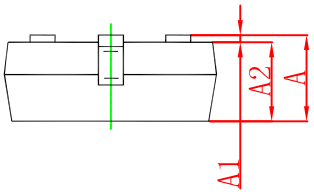






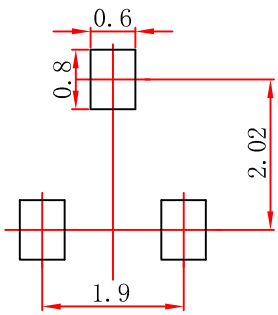






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.